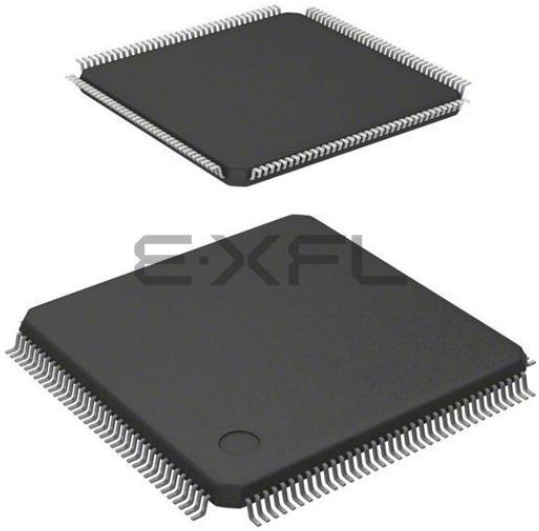

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Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	e200z0h
Core Size	32-Bit Single-Core
Speed	64MHz
Connectivity	CANbus, LINbus, SPI, UART/USART
Peripherals	DMA, POR, PWM, WDT
Number of I/O	80
Program Memory Size	768KB (768K x 8)
Program Memory Type	FLASH
EEPROM Size	64K x 8
RAM Size	64K x 8
Voltage - Supply (Vcc/Vdd)	4.5V ~ 5.5V
Data Converters	A/D 26x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 125°C (TA)
Mounting Type	Surface Mount
Package / Case	144-LQFP
Supplier Device Package	144-LQFP (20x20)
Purchase URL	https://www.e-xfl.com/product-detail/stmicroelectronics/spc560p54l5cefar

Table 1. Device summary

Package	Part number	
	768 KB Flash	1 MB Flash
LQFP144	SPC560P54L5 SPC56AP54L5	SPC560P60L5 SPC56AP60L5
LQFP100	SPC560P54L3 SPC56AP54L3	SPC560P60L3 SPC56AP60L3

List of figures

Table 4. SPC56xP54x/SPC56xP60x series block summary (continued)

Block	Function
Peripheral bridge (PBRIDGE)	Is the interface between the system bus and on-chip peripherals
Periodic interrupt timer (PIT)	Produces periodic interrupts and triggers
Power control unit (MC_PCU)	Reduces the overall power consumption by disconnecting parts of the device from the power supply via a power switching device; device components are grouped into sections called “power domains” which are controlled by the PCU
Reset generation module (MC_RGM)	Centralizes reset sources and manages the device reset sequence of the device
Semaphore unit (SEMA4)	Provides the hardware support needed in multi-core systems for implementing semaphores and provide a simple mechanism to achieve lock/unlock operations via a single write access
Static random-access memory (SRAM)	Provides storage for program code, constants, and variables
System integration unit lite (SIUL)	Provides control over all the electrical pad controls and up 32 ports with 16 bits of bidirectional, general-purpose input and output signals and supports up to 32 external interrupts with trigger event configuration
System status and configuration module (SSCM)	Provides system configuration and status data (such as memory size and status, device mode and security status), device identification data, debug status port enable and selection, and bus and peripheral abort enable/disable
System timer module (STM)	Provides a set of output compare events to support AUTOSAR(1) and operating system tasks
System watchdog timer (SWT)	Provides protection from runaway code
Wakeup unit (WKPU)	Supports up to 18 external sources that can generate interrupts or wakeup events, of which 1 can cause non-maskable interrupt requests or wakeup events.

1. AUTOSAR: AUTomotive Open System ARchitecture (see autosar.org web site).

1.5.13 Software watchdog timer (SWT)

The SWT has the following features:

- Fault tolerant output
- Safe internal RC oscillator as reference clock
- Windowed watchdog
- Program flow control monitor with 16-bit pseudorandom key generation

The SWT module is replicated for each processor.

1.5.14 Fault collection and control unit (FCCU)

The FCCU provides an independent fault reporting mechanism even if the CPU is exhibiting unstable behaviors. The FCCU module has the following features:

- Redundant collection of hardware checker results
- Redundant collection of error information and latch of faults from critical modules on the device
- Collection of self-test results
- Configurable and graded fault control
  - Internal reactions (no internal reaction, IRQ)
  - External reaction (failure is reported to the external/surrounding system via configurable output pins)

1.5.15 System integration unit (SIUL)

The SPC56xP54x/SPC56xP60x SIUL controls MCU pad configuration, external interrupts, general purpose I/O (GPIO) pin configuration, and internal peripheral multiplexing.

The pad configuration block controls the static electrical characteristics of I/O pins. The GPIO block provides uniform and discrete input/output control of the I/O pins of the MCU.

The SIUL provides the following features:

- Centralized general purpose input output (GPIO) control of input/output pins and analog input-only pads (package dependent)
- All GPIO pins can be independently configured to support pull-up, pull down, or no pull
- Reading and writing to GPIO supported both as individual pins and 16-bit wide ports
- All peripheral pins (except ADC channels) can be alternatively configured as both general purpose input or output pins
- ADC channels support alternative configuration as general purpose inputs
- Direct readback of the pin value is supported on all pins through the SIU
- Configurable digital input filter that can be applied to some general purpose input pins for noise elimination
  - Up to 4 internal functions can be multiplexed onto one pin

1.5.16 Boot and censorship

Different booting modes are available in the SPC56xP54x/SPC56xP60x:

- From internal flash memory
- Via a serial link

Table 7. Pin muxing[1] (continued)

Port pin	PCR No.	Alternate function[2], [3]	Functions	Peripheral [4]	I/O direction [5]	Pad speed[6]		Pin		
						SRC = 0	SRC = 1	LQFP 100	LQFP 144	LQFP 176[7]
Port B										
B[0]	PCR[16]	ALT0 ALT1 ALT2 ALT3 —	GPIO[16] TXD ETC[2] DEBUG[0] EIRQ[15]	SIUL FlexCAN_0 eTimer_1 SSCM SIUL	I/O O I/O — I	Slow	Medium	76	109	133
B[1]	PCR[17]	ALT0 ALT1 ALT2 ALT3 — —	GPIO[17] CS7_1 ETC[3] DEBUG[1] RXD EIRQ[16]	SIUL DSPI_1 eTimer_1 SSCM FlexCAN_0 SIUL	I/O O I/O — I I	Slow	Medium	77	110	134
B[2]	PCR[18]	ALT0 ALT1 ALT2 ALT3 —	GPIO[18] TXD SOUT_4 DEBUG[2] EIRQ[17]	SIUL LINFlex_0 DSPI_4 SSCM SIUL	I/O O I/O — I	Slow	Medium	79	114	138
B[3]	PCR[19]	ALT0 ALT1 ALT2 ALT3 —	GPIO[19] — SCK_4 DEBUG[3] RXD	SIUL — DSPI_4 SSCM LINFlex_0	I/O — I/O — I	Slow	Medium	80	116	140
B[6]	PCR[22]	ALT0 ALT1 ALT2 ALT3 —	GPIO[22] clk_out CS2_2 clk_out_div256 EIRQ[18]	SIUL MC_CGL DSPI_2 MC_CGL SIUL	I/O O O O I	Slow	Medium	96	138	162
B[7]	PCR[23]	ALT0 ALT1 ALT2 ALT3 — —	GPIO[23] — — — AN[0] RXD	SIUL — — — ADC_0 LINFlex_0	Input Only	—	—	29	43	51
B[8]	PCR[24]	ALT0 ALT1 ALT2 ALT3 — —	GPIO[24] — — — AN[1] ETC[5]	SIUL — — — ADC_0 eTimer_0	Input Only	—	—	31	47	55

Table 7. Pin muxing[1] (continued)

Port pin	PCR No.	Alternate function[2], [3]	Functions	Peripheral [4]	I/O direction [5]	Pad speed[6]		Pin		
						SRC = 0	SRC = 1	LQFP 100	LQFP 144	LQFP 176[7]
Port C										
C[0]	PCR[32]	ALT0 ALT1 ALT2 ALT3 —	GPIO[32] — — — AN[19]	SIUL — — — ADC_0	Input Only	—	—	45	66	78
C[1]	PCR[33]	ALT0 ALT1 ALT2 ALT3 —	GPIO[33] — — — AN[2]	SIUL — — — ADC_0	Input Only	—	—	28	41	49
C[2]	PCR[34]	ALT0 ALT1 ALT2 ALT3 —	GPIO[34] — — — AN[3]	SIUL — — — ADC_0	Input Only	—	—	30	45	53
C[3]	PCR[35]	ALT0 ALT1 ALT2 ALT3 —	GPIO[35] CS1_0 ETC[4] TXD EIRQ[21]	SIUL DSPI_0 eTimer_1 LINFlex_1 SIUL	I/O O I/O O I	Slow	Medium	10	16	24
C[4]	PCR[36]	ALT0 ALT1 ALT2 ALT3 —	GPIO[36] CS0_0 — DEBUG[4] EIRQ[22]	SIUL DSPI_0 — SSCM SIUL	I/O I/O — — I	Slow	Medium	5	11	19
C[5]	PCR[37]	ALT0 ALT1 ALT2 ALT3 —	GPIO[37] SCK_0 SCK_4 DEBUG[5] EIRQ[23]	SIUL DSPI_0 DSPI_4 SSCM SIUL	I/O I/O I/O — I	Slow	Medium	7	13	21
C[6]	PCR[38]	ALT0 ALT1 ALT2 ALT3 —	GPIO[38] SOUT_0 — DEBUG[6] EIRQ[24]	SIUL DSPI_0 — SSCM SIUL	I/O O — — I	Slow	Medium	98	142	174

Table 7. Pin muxing[1] (continued)

Port pin	PCR No.	Alternate function[2], [3]	Functions	Peripheral [4]	I/O direction [5]	Pad speed[6]		Pin		
						SRC = 0	SRC = 1	LQFP 100	LQFP 144	LQFP 176[7]
C[15]	PCR[47]	ALT0 ALT1 ALT2 ALT3 —	GPIO[47] CA_TR_EN ETC[0] — EXT_IN	SIUL FlexRay_0 eTimer_1 — CTU_0	I/O O I/O — I	Slow	Symmetric	85	124	148
Port D										
D[0]	PCR[48]	ALT0 ALT1 ALT2 ALT3	GPIO[48] CA_TX ETC[1] —	SIUL FlexRay_0 eTimer_1 —	I/O O I/O —	Slow	Symmetric	86	125	149
D[1]	PCR[49]	ALT0 ALT1 ALT2 ALT3 —	GPIO[49] CS4_1 ETC[2] EXT_TRG CA_RX	SIUL DSPI_1 eTimer_1 CTU_0 FlexRay_0	I/O O I/O O I	Slow	Medium	3	3	3
D[2]	PCR[50]	ALT0 ALT1 ALT2 ALT3 —	GPIO[50] CS5_1 ETC[3] — CB_RX	SIUL DSPI_1 eTimer_1 — FlexRay_0	I/O O I/O — I	Slow	Medium	97	140	168
D[3]	PCR[51]	ALT0 ALT1 ALT2 ALT3	GPIO[51] CB_TX ETC[4] —	SIUL FlexRay_0 eTimer_1 —	I/O O I/O —	Slow	Symmetric	89	128	152
D[4]	PCR[52]	ALT0 ALT1 ALT2 ALT3	GPIO[52] CB_TR_EN ETC[5] —	SIUL FlexRay_0 eTimer_1 —	I/O O I/O —	Slow	Symmetric	90	129	153
D[5]	PCR[53]	ALT0 ALT1 ALT2 ALT3	GPIO[53] CS3_0 — SOUT_3	SIUL DSPI_0 — DSPI_3	I/O O — O	Slow	Medium	22	33	41
D[6]	PCR[54]	ALT0 ALT1 ALT2 ALT3	GPIO[54] CS2_0 SCK_3 SOUT_4	SIUL DSPI_0 DSPI_3 DSPI_4	I/O O I/O O	Slow	Medium	23	34	42

Table 10. Recommended operating conditions (5.0 V) (continued)

Symbol		Parameter	Conditions	Min	Max(1)	Unit
$V_{DD\_HV\_REG}$	SR	5.0 V voltage regulator supply voltage	—	4.5	5.5	V
			Relative to $V_{DD\_HV\_IOx}$	$V_{DD\_HV\_IOx}$ – 0.1	$V_{DD\_HV\_IOx}$ + 0.1	
$V_{DD\_HV\_AD}$	SR	5.0 V ADC supply and high reference voltage	—	4.5	5.5	V
			Relative to $V_{DD\_HV\_REG}$	$V_{DD\_HV\_REG}$ – 0.1	—	
$V_{SS\_HV\_AD}$	SR	ADC ground and low reference voltage	—	0	0	V
$V_{DD\_LV\_REGCOR}$(3),(4)	SR	Internal supply voltage	—	—	—	V
$V_{SS\_LV\_REGCOR}$(3)	SR	Internal reference voltage	—	0	0	V
$V_{DD\_LV\_CORx}$(3),(4)	SR	Internal supply voltage	—	—	—	V
$V_{SS\_LV\_CORx}$(3)	SR	Internal reference voltage	—	0	0	V
T_A	SR	Ambient temperature under bias	—	–40	125	°C

1. Parametric figures can be out of specification when voltage drops below 4.5 V, however, guaranteeing the full functionality. In particular, ADC electrical characteristics and I/Os DC electrical specification may not be guaranteed.
2. The difference between each couple of voltage supplies must be less than 100 mV, $|V_{DD\_HV\_IOy} – V_{DD\_HV\_IOx}| < 100$ mV.
3. To be connected to emitter of external NPN. Low voltage supplies are not under user control—these are produced by an on-chip voltage regulator—but for the device to function properly the low voltage grounds ($V_{SS\_LV\_xxx}$) must be shorted to high voltage grounds ($V_{SS\_HV\_xxx}$) and the low voltage supply pins ($V_{DD\_LV\_xxx}$) must be connected to the external ballast emitter.
4. The low voltage supplies ($V_{DD\_LV\_xxx}$) are not all independent. $V_{DD\_LV\_COR1}$ and $V_{DD\_LV\_COR2}$ are shorted internally via double bonding connections with lines that provide the low voltage supply to the data flash memory module. Similarly, $V_{SS\_LV\_COR1}$ and $V_{SS\_LV\_COR2}$ are internally shorted. $V_{DD\_LV\_REGCOR}$ and $V_{DD\_LV\_REGCORx}$ are physically shorted internally, as are $V_{SS\_LV\_REGCOR}$ and $V_{SS\_LV\_CORx}$.

Table 11. Recommended operating conditions (3.3 V)

Symbol		Parameter	Conditions	Min	Max(1)	Unit
V_{SS_HV}	SR	Digital ground	—	0	0	V
$V_{DD\_HV\_IOx}$(2)	SR	3.3 V input/output supply voltage	—	3.0	3.6	V
$V_{SS\_HV\_IOx}$	SR	Input/output ground voltage	—	0	0	V
$V_{DD\_HV\_FL}$	SR	3.3 V code and data flash memory supply voltage	—	3.0	3.6	V
			Relative to $V_{DD\_HV\_IOx}$	$V_{DD\_HV\_IOx}$ – 0.1	$V_{DD\_HV\_IOx}$ + 0.1	
$V_{SS\_HV\_FL}$	SR	Code and data flash memory ground	—	0	0	V
$V_{DD\_HV\_OSC}$	SR	3.3 V crystal oscillator amplifier supply voltage	—	3.0	3.6	V
			Relative to $V_{DD\_HV\_IOx}$	$V_{DD\_HV\_IOx}$ – 0.1	$V_{DD\_HV\_IOx}$ + 0.1	
$V_{SS\_HV\_OSC}$	SR	3.3 V crystal oscillator amplifier reference voltage	—	0	0	V

Figure 10. Power-up typical sequence

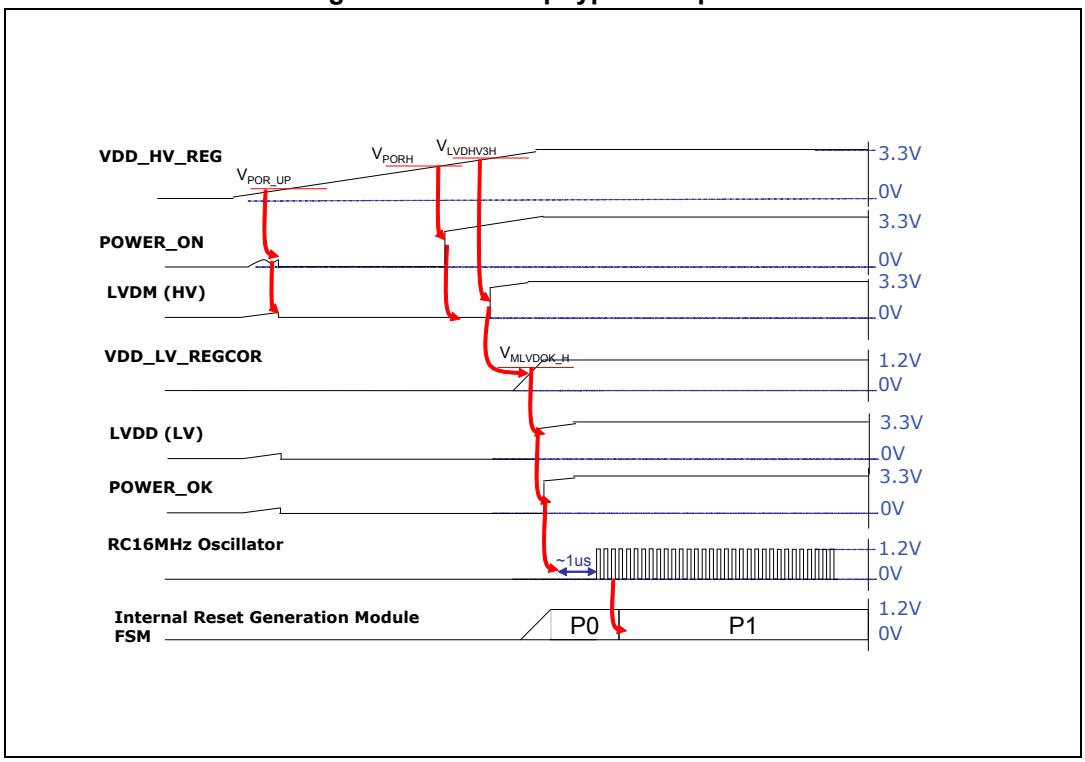


Figure 11. Power-down typical sequence

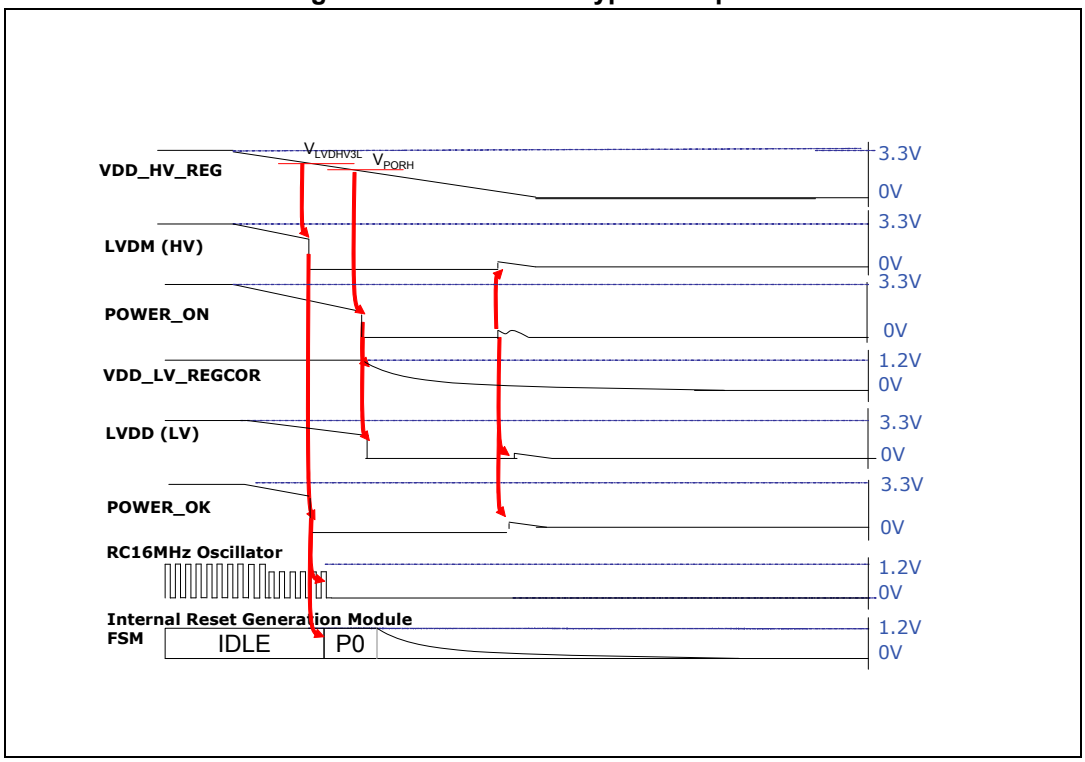
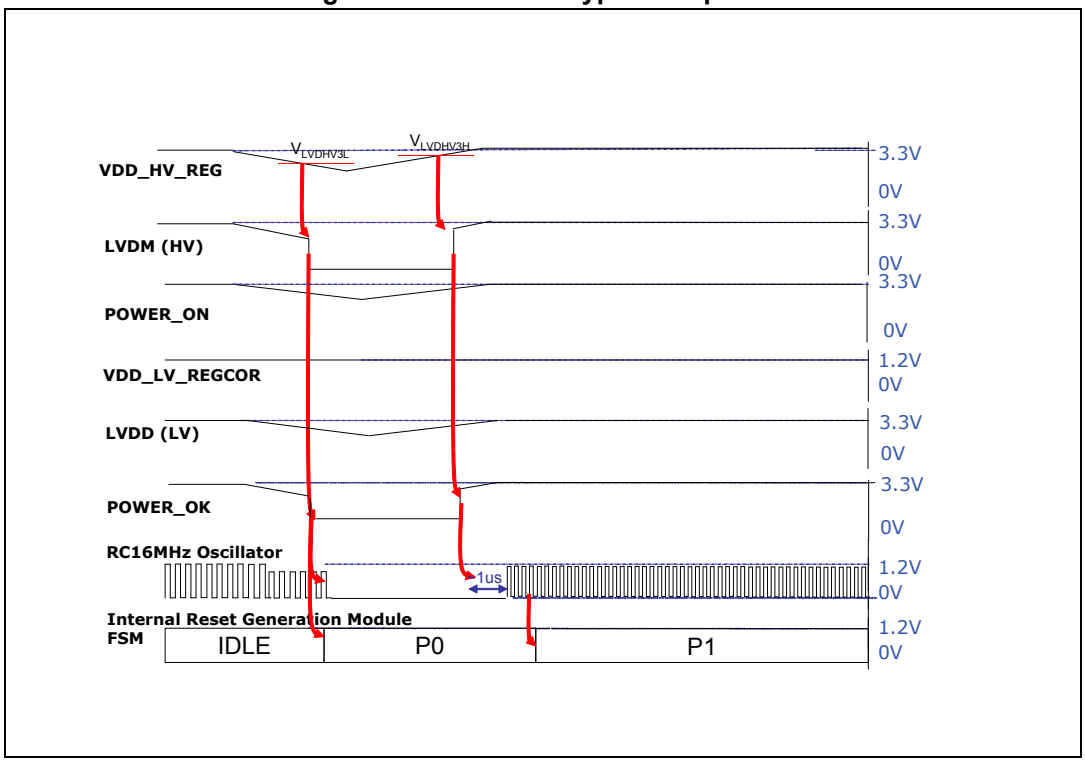


Figure 12. Brown-out typical sequence



3.10 NVUSRO register

Portions of the device configuration, such as high voltage supply, and watchdog enable/disable after reset are controlled via bit values in the non-volatile user options register (NVUSRO) register.

For a detailed description of the NVUSRO register, please refer to the device reference manual.

3.10.1 NVUSRO[PAD3V5V] field description

Table 19 shows how NVUSRO[PAD3V5V] controls the device configuration.

Table 19. PAD3V5V field description(1)

Value(2)	Description
0	High voltage supply is 5.0 V
1	High voltage supply is 3.3 V

1. See the device reference manual for more information on the NVUSRO register.
2. '1' is delivery value. It is part of shadow Flash, thus programmable by customer.

The DC electrical characteristics are dependent on the PAD3V5V bit value.

Table 29. Input clock characteristics

Symbol		Parameter	Min	Typ	Max	Unit
f_{OSC}	SR	Oscillator frequency	4	—	40	MHz
f_{CLK}	SR	Frequency in bypass	—	—	64	MHz
t_{rCLK}	SR	Rise/fall time in bypass	—	—	1	ns
t_{DC}	SR	Duty cycle	47.5	50	52.5	%

3.13 FMPLL electrical characteristics

Table 30. PLLMRFM electrical specifications (V_{DDPLL} = 1.08 V to 1.32 V, V_{SS} = V_{SSPLL} = 0 V, T_A = T_L to T_H)

Symbol		Parameter		Conditions	Value		Unit
					min	max	
$f_{ref\_crystal}$ f_{ref_ext}	D	PLL reference frequency range(1)		Crystal reference	4	40	MHz
f_{pll_in}	D	Phase detector input frequency range (after pre-divider)		—	4	16	MHz
$f_{FMPLLOUT}$	D	Clock frequency range in normal mode		—	4	120	MHz
f_{FREE}	P	Free running frequency		Measured using clock division — typically /16	20	150	MHz
f_{sys}	D	On-chip PLL frequency		—	16	64	MHz
t_{CYC}	D	System clock period		—	—	1 / f_{sys}	ns
f_{LORL} f_{LORH}	D	Loss of reference frequency window(2)		Lower limit	1.6	3.7	MHz
				Upper limit	24	56	
f_{SCM}	D	Self-clocked mode frequency(3),(4)		—	20	150	MHz
C_{JITTER}	T	CLKOUT period jitter(5),(6),(7),(8)	Short-term jitter(9)	f_{SYS} maximum	–4	4	% f_{CLKOUT}
			Long-term jitter (avg. over 2 ms interval)	f_{PLLIN} = 16 MHz (resonator), f_{PLLCLK} at 64 MHz, 4000 cycles	—	10	ns
t_{lpll}	D	PLL lock time (10), (11)		—	—	200	µs
t_{dc}	D	Duty cycle of reference		—	40	60	%
f_{LCK}	D	Frequency LOCK range		—	–6	6	% f_{sys}
f_{UL}	D	Frequency un-LOCK range		—	–18	18	% f_{sys}
f_{CS} f_{DS}	D	Modulation Depth		Center spread	±0.25	±4.0(12)	%f_{sys}
				Down Spread	–0.5	–8.0	
f_{MOD}	D	Modulation frequency(13)		—	—	70	kHz

1. Considering operation with PLL not bypassed.

2. “Loss of Reference Frequency” window is the reference frequency range outside of which the PLL is in self clocked mode.
3. Self clocked mode frequency is the frequency that the PLL operates at when the reference frequency falls outside the f_{LOR} window.
4. f_{VCO} self clock range is 20–150 MHz. f_{SCM} represents f_{SYS} after PLL output divider (ERFD) of 2 through 16 in enhanced mode.
5. This value is determined by the crystal manufacturer and board design.
6. Jitter is the average deviation from the programmed frequency measured over the specified interval at maximum f_{SYS}. Measurements are made with the device powered by filtered supplies and clocked by a stable external clock signal. Noise injected into the PLL circuitry via V_{DDPLL} and V_{SSPLL} and variation in crystal oscillator frequency increase the C_{JITTER} percentage for a given interval.
7. Proper PC board layout procedures must be followed to achieve specifications.
8. Values are obtained with frequency modulation disabled. If frequency modulation is enabled, jitter is the sum of C_{JITTER} and either f_{CS} or f_{DS} (depending on whether center spread or down spread modulation is enabled).
9. Short term jitter is measured on the clock rising edge at cycle n and cycle n+4.
10. This value is determined by the crystal manufacturer and board design. For 4 MHz to 20 MHz crystals specified for this PLL, load capacitors should not exceed these limits.
11. This specification applies to the period required for the PLL to relock after changing the MFD frequency control bits in the synthesizer control register (SYNCR).
12. This value is true when operating at frequencies above 60 MHz, otherwise f_{CS} is 2% (above 64 MHz).
13. Modulation depth will be attenuated from depth setting when operating at modulation frequencies above 50 kHz.

3.14 16 MHz RC oscillator electrical characteristics

Table 31. 16 MHz RC oscillator electrical characteristics

Symbol		Parameter	Conditions	Min	Typ	Max	Unit
f_{RC}	P	RC oscillator frequency	T_A = 25 °C	—	16	—	MHz
Δ_{RCMVAR}	P	Fast internal RC oscillator variation over temperature and supply with respect to f_{RC} at T_A = 25 °C in high-frequency configuration	—	–6	—	6	%
$\Delta_{RCMTRIM}$	T	Post Trim Accuracy: The variation of the PTF(1) from the 16 MHz	T_A = 25 °C	–1	—	1	%
$\Delta_{RCMSTEP}$	T	Fast internal RC oscillator trimming step	T_A = 25 °C	—	1.6	—	%

1. PTF = Post Trimming Frequency: The frequency of the output clock after trimming at typical supply voltage and temperature

3.15 Analog-to-Digital converter (ADC) electrical characteristics

The device provides a 10-bit Successive Approximation Register (SAR) Analog-to-Digital Converter.

Table 32. ADC conversion characteristics (continued)

Symbol		Parameter	Conditions[1]	Value			Unit
				Min	Typ	Max	
TUE	T	Total unadjusted error with current injection	16 precision channels	–3	—	3	LSB
TUE	T	Total unadjusted error with current injection	10 standard channels	–4	—	4	LSB

1. V_{DD} = 3.3 V to 3.6 V / 4.5 V to 5.5 V, T_A = –40 °C to $T_{A\ MAX}$, unless otherwise specified and analog input voltage from $V_{SS\_HV\_AD}$ to $V_{DD\_HV\_AD}$.
2. V_{INAN} may exceed V_{SS_ADC} and V_{DD_ADC} limits, remaining on absolute maximum ratings, but the results of the conversion will be clamped respectively to 0x000 or 0x3FF.
3. AD_clk clock is always half of the ADC module input clock defined via the auxiliary clock divider for the ADC.
4. When configured to allow 60 MHz ADC, the minimum ADC clock speed is 9 MHz, below which precision is lost.
5. During the sample time the input capacitance CS can be charged/discharged by the external source. The internal resistance of the analog source must allow the capacitance to reach its final voltage level within t_{ADC_S}. After the end of the sample time t_{ADC_S}, changes of the analog input voltage have no effect on the conversion result. Values for the sample clock t_{ADC_S} depend on programming.
6. This parameter includes the sample time t_{ADC_S}.
7. 20 MHz ADC clock. Specific prescaler is programmed on MC_PLL_CLK to provide 20 MHz clock to the ADC.
8. See *Figure 16*.

3.16 Flash memory electrical characteristics

Table 33. Program and erase specifications

Symbol		Parameter	Conditions	Value				Unit
				Min	Typ[1]	Initial max[2]	Max[3]	
$T_{wprogram}$	P	Word Program (32 bits) Time[4]	Data Flash	—	30	70	500	µs
$T_{dwprogram}$	P	Double Word (64 bits) Program Time[4]	Code Flash	—	18	50	500	µs
T_{BKPRG}	P	Bank Program (64 KB)[4, 5]	Data Flash	—	0.49	1.2	4.1	s
	P	Bank Program (1056 KB)[4, 5]	Code Flash	—	2.6	6.6	66	s
T_{MDPRG}	P	Module Program (512 KB)[4]	Code Flash	—	1.3	1.65	33	s
$T_{16kpperase}$	P	16 KB Block Pre-program and Erase Time	Code Flash	—	200	500	5000	ms
			Data Flash		700	800		
$T_{32kpperase}$	P	32 KB Block Pre-program and Erase Time	Code Flash	—	300	600	5000	ms
$T_{64kpperase}$	P	64 KB Block Pre-program and Erase Time	Code Flash	—	400	900	5000	ms
$T_{128kpperase}$	P	128 KB Block Pre-program and Erase Time	Code Flash	—	600	1300	5000	ms
t_{ESRT}	P	Erase Suspend Request Rate[6]	Code Flash	20	—	—	—	ms
			Data Flash	10				

1. Typical program and erase times assume nominal supply values and operation at 25 °C. All times are subject to change pending device characterization.
2. Initial factory condition: < 100 program/erase cycles, 25 °C, typical supply voltage.

3.17 AC specifications

3.17.1 Pad AC specifications

Table 36. Output pin transition times

Symbol		C	Parameter	Conditions[1]		Value			Unit
						Min	Typ	Max	
T_{tr}	CC	D	Output transition time output pin[2] SLOW configuration	C_L = 25 pF	V_{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	50	ns
		T		C_L = 50 pF		—	—	100	
		D		C_L = 100 pF		—	—	125	
		D		C_L = 25 pF	V_{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	40	
		T		C_L = 50 pF		—	—	50	
		D		C_L = 100 pF		—	—	75	
T_{tr}	CC	D	Output transition time output pin[2] MEDIUM configuration	C_L = 25 pF	V_{DD} = 5.0 V ± 10%, PAD3V5V = 0 SIUL.PCRx.SRC = 1	—	—	10	ns
		T		C_L = 50 pF		—	—	20	
		D		C_L = 100 pF		—	—	40	
		D		C_L = 25 pF	V_{DD} = 3.3 V ± 10%, PAD3V5V = 1 SIUL.PCRx.SRC = 1	—	—	12	
		T		C_L = 50 pF		—	—	25	
		D		C_L = 100 pF		—	—	40	
T_{tr}	CC	D	Output transition time output pin[2] FAST configuration	C_L = 25 pF	V_{DD} = 5.0 V ± 10%, PAD3V5V = 0 SIUL.PCRx.SRC = 1	—	—	4	ns
				C_L = 50 pF		—	—	6	
				C_L = 100 pF		—	—	12	
				C_L = 25 pF	V_{DD} = 3.3 V ± 10%, PAD3V5V = 1 SIUL.PCRx.SRC = 1	—	—	4	
				C_L = 50 pF		—	—	7	
				C_L = 100 pF		—	—	12	
T_{sim}[3]	CC	T	Symmetric, same drive strength between N and P transistor	V_{DD} = 5.0 V ± 10%, PAD3V5V = 0		—	—	4	ns
				V_{DD} = 3.3 V ± 10%, PAD3V5V = 1		—	—	5	

1. V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = –40 °C to $T_{A\ MAX}$, unless otherwise specified.
2. C_L includes device and package capacitances (C_{PKG} < 5 pF).
3. Transition timing of both positive and negative slopes will differ maximum 50 %.

3.18 AC timing characteristics

3.18.1 $\overline{\text{RESET}}$ pin characteristics

The SPC56xP54x/SPC56xP60x implements a dedicated bidirectional RESET pin.

Table 39. Nexus debug port timing(1) (continued)

No.	Symbol		C	Parameter	Value			Unit
					Min	Typ	Max	
6	t_{NTDIS}	CC	D	TDI data setup time	6	—	—	ns
	t_{NTMSS}	CC	D	TMS data setup time	6	—	—	ns
7	t_{NTDIH}	CC	D	TDI data hold time	10	—	—	ns
	t_{NTMSH}	CC	D	TMS data hold time	10	—	—	ns
8	t_{TDOV}	CC	D	TCK low to TDO data valid	—	—	35	ns
9	t_{TDOI}	CC	D	TCK low to TDO data invalid	6	—	—	ns

1. All values need to be confirmed during device validation.
2. Lower frequency is required to be fully compliant to standard.

Figure 25. Nexus output timing

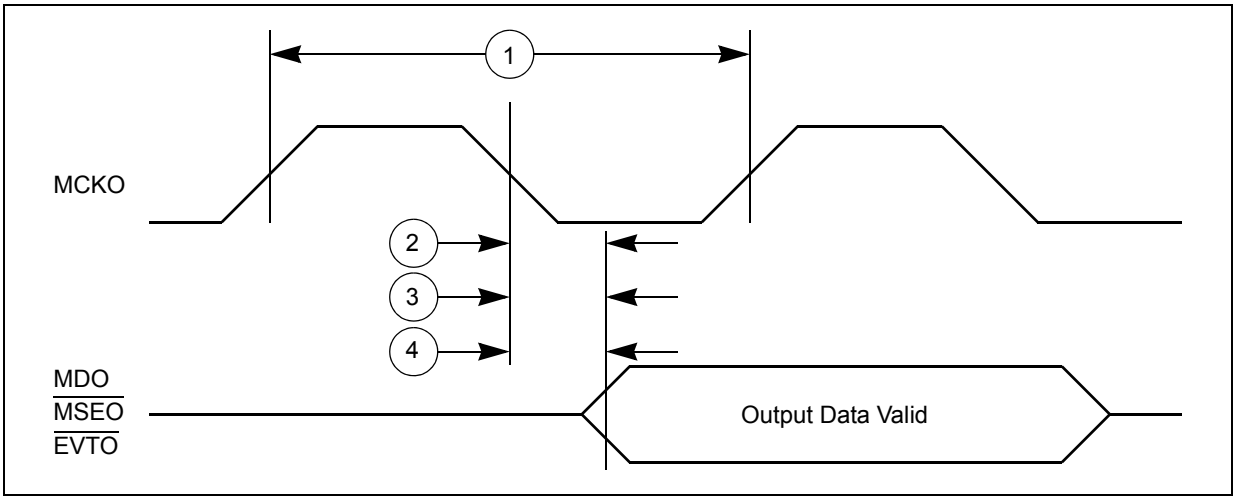
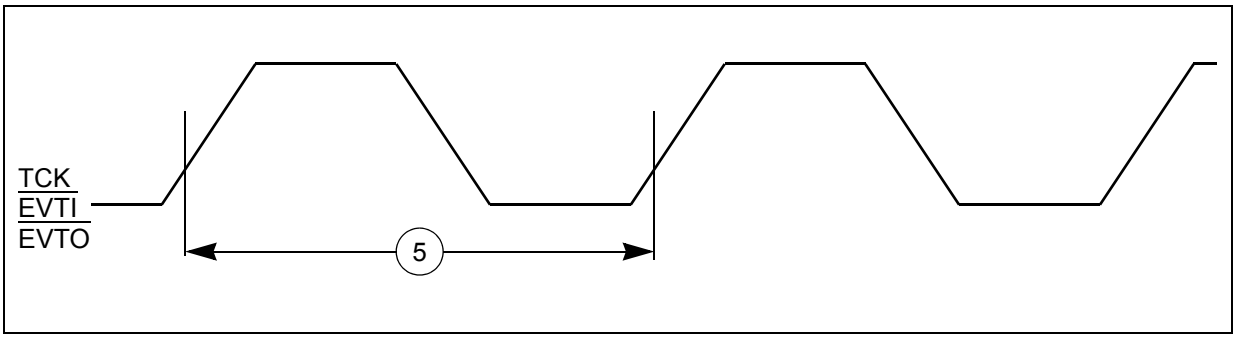


Figure 26. Nexus event trigger and test clock timings



4 Package characteristics

4.1 ECOPACK®

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK® is an ST trademark.

4.2 Package mechanical data

4.2.1 LQFP144 mechanical outline drawing

Figure 38. LQFP144 package mechanical drawing

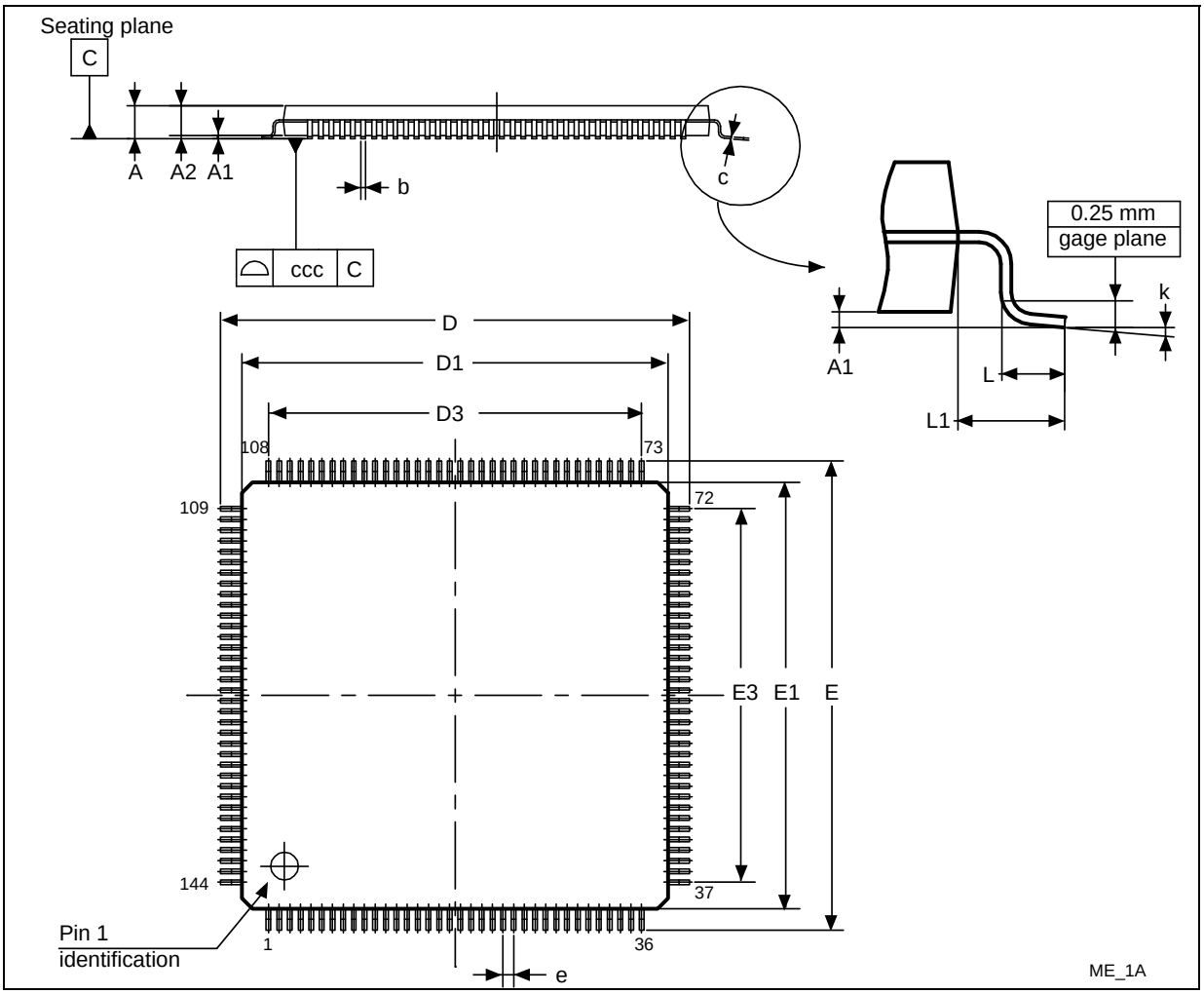


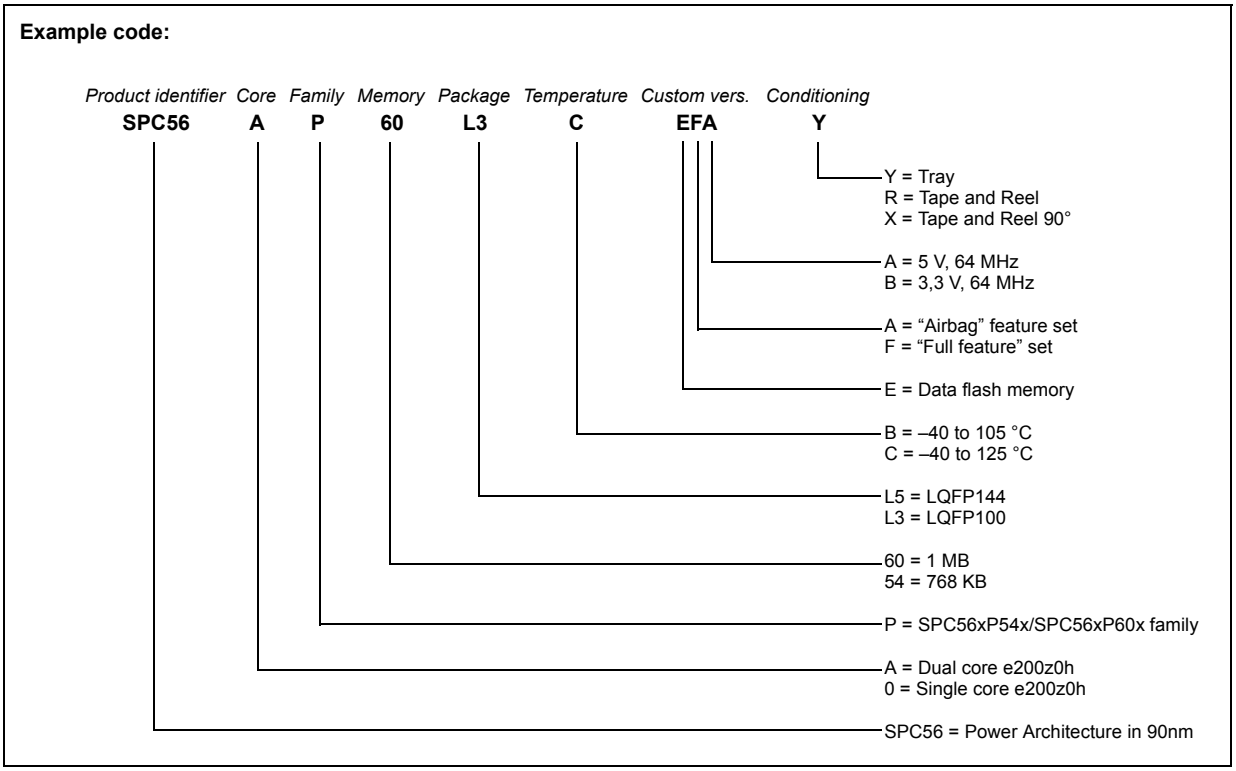
Table 42. LQFP144 mechanical data

Symbol	mm			inches[1]		
	Min	Typ	Max	Min	Typ	Max
A	—	—	1.600	—	—	0.0630
A1	0.050	—	0.150	0.0020	—	0.0059
A2	1.350	1.400	1.450	0.0531	0.0551	0.0571
b	0.170	0.220	0.270	0.0067	0.0087	0.0106
c	0.090	—	0.200	0.0035	—	0.0079
D	21.800	22.000	22.200	0.8583	0.8661	0.8740
D1	19.800	20.000	20.200	0.7795	0.7874	0.7953
D3	—	17.500	—	—	0.6890	—
E	21.800	22.000	22.200	0.8583	0.8661	0.8740
E1	19.800	20.000	20.200	0.7795	0.7874	0.7953
E3	—	17.500	—	—	0.6890	—
e	—	0.500	—	—	0.0197	—
L	0.450	0.600	0.750	0.0177	0.0236	0.0295
L1	—	1.000	—	—	0.0394	—
k	0.0 °	3.5 °	7.0°	3.5 °	0.0 °	7.0 °
ccc[2]	0.080			0.0031		

1. Values in inches are converted from mm and rounded to 4 decimal digits.
2. Tolerance.

5 Ordering information

Figure 40. Ordering information scheme(h)



h. Not all configurations are available on the market. Please contact your ST sales representative to get the list of orderable commercial part number.

Table 44. Document revision history (continued)

Date	Revision	Substantive changes
15-May-2012	3	Removed “Enhanced Full-featured” version. In the cover page, added “(1 × Master/Slave, 1 × Master Only)“ at the end of the bullet “2 LINFlex modules (LIN 2.1)” *Table 2: SPC56xP54x/SPC56xP60x device comparison*, updated the value of “LINFLEX module” to “2 (1 × Master/Slave, 1 × Master only)” *Section 1.5.4: On-chip flash memory with ECC* replaced two occurrences of “3 wait states” to “2 wait states” replaced 60 MHz to 64 MHz *Section 1.5.21: Serial communication interface module (LINFlex)*, updated first bullet to “Supports LIN Master mode (on both modules), LIN Slave mode (on one module) and UART mode” *Section 1.5.24: Analog-to-digital converter (ADC)*, removed bullet concerning the analog watchdogs from Normal mode features. *Table 5: Supply pins*, removed V_{REG_BYPASS} row. *Table 6: System pins*: added V_{REG_BYPASS} row added a footnote about $\overline{RESET}$ *Table 9: Absolute maximum ratings*: changed typical value of TV_{DD} to 0.25 and added a footnote added V_{INAN} entry Updated *Section 3.8.1: Voltage regulator electrical characteristics* Updated *Table 14: EMI testing specifications* *Table 18: Low voltage monitor electrical characteristics*, changed maximum value of $V_{MLVDDOK\_H}$ to 1.15 *Table 20: DC electrical characteristics (5.0 V, NVUSRO[PAD3V5V]=0)*, added IPU and IPD rows for $\overline{RESET}$ pin. *Table 21: Supply current (5.0 V, NVUSRO[PAD3V5V]=0)*: added maximum values of $I_{DD\_LV\_CORE}$ for: RUN, HALT, and STOP mode updated values and parameter classification of I_{DD_FLASH} *Table 22: DC electrical characteristics (3.3 V, NVUSRO[PAD3V5V]=1)*, added IPU and IPD rows for $\overline{RESET}$ pin. *Table 23: Supply current (3.3 V, NVUSRO[PAD3V5V]=1)*: added maximum values of $I_{DD\_LV\_CORE}$ for: RUN, HALT, and STOP mode updated values and parameter classification of I_{DD_FLASH} Added *Table 26: I/O consumption* *Table 31: 16 MHz RC oscillator electrical characteristics*, changed minimum and maximum values of Δ_{RCMVAR} respectively to -6 and 6. Renamed *Figure 16: Input equivalent circuit (precise channels)* (was “Input equivalent circuit”) Added *Figure 17: Input equivalent circuit (extended channels)* *Section 3.15.1: Input impedance and ADC accuracy*, updated *Equation 4* and *Equation 10* *Table 32: ADC conversion characteristics*, added V_{INAN}, C_{P3} and R_{SW2} rows